TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7SZ04F,TC7SZ04FU

Inverter

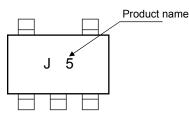
Features

- High output drive: ±24 mA (min) at V_{CC} = 3 V
- Super high speed operation: tpd=2.4 ns (typ.)

at V_{CC} = 5 V, 50 pF

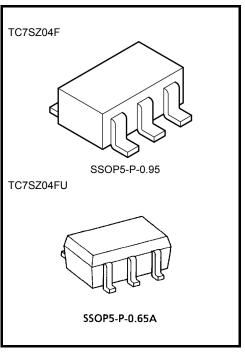
- Operation voltage range: V_{CC (opr)} = 1.8~5.5 V
- 5.5-V tolerant inputs
- 5.5-V power down protection output
- Matches the performance of TC74LCX series when operated at 3.3- V V_{CC}

Marking



Absolute Maximum Ratings (Ta = 25°C)

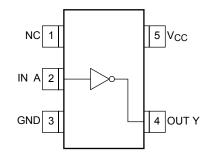
Characteristics	Symbol	Rating	Unit	
Supply voltage range	V _{CC}	-0.5~6	V	
DC input voltage	V _{IN}	-0.5~6	V	
DC output voltage	V _{OUT}	$-0.5 \sim V_{CC} + 0.5$	V	
Input diode current	I _{IK}	-20	mA	
Output diode current	IOK	±20	mA	
DC output current	IOUT	±50	mA	
DC V _{CC} /ground current	ICC	±50	mA	
Power dissipation	PD	200	mW	
Storage temperature	T _{stg}	-65~150	°C	
Lead temperature (10 s)	ΤL	260	°C	



Weight SSOP5-P-0.95 : 0.016 g (typ.)

SSOP5-P-0.65A: 0.006 g (typ.)

Pin Assignment (top view)

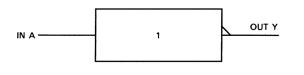


Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

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Logic Diagram



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Truth Table



Operating Ranges

Characteristics	Symbol	Rating	Unit	
Supply voltage	V _{CC}	1.8~5.5	V	
		1.5~5.5 (Note 1)	v	
Input voltage	V _{IN}	0~5.5	V	
Output voltage	V _{OUT}	0~5.5 (Note 2)	V	
		0~V _{CC} (Note 3)	v	
Operating temperature	T _{opr}	-40~85	°C	
		0~20 (V _{CC} = 1.8 V, 2.5 V \pm 0.2 V)	ns/V	
Input rise and fall time	dt/dv	0~10 (V_{CC} = 3.3 V \pm 0.3 V)		
		0~5 (V _{CC} = 5.5 V \pm 0.5 V)		

Note 1: Data retention only

Note 2: $V_{CC} = 0 V$

Note 3: High or Low state

Electrical Characteristics

DC Characteristics

Characteristics Symbol Test Condition		est Condition		Ta = 25°C			Ta = -40~85°C		Unit	
		Te	V _{CC} (V)		Min	Тур.	Max	Min	Max	Unit
High-level input VIH —		1.8	V _{CC} × 0.88	_	_	V _{CC} × 0.88	_	v		
		—	2.3~5.5	V _{CC} × 0.75	_	_	V _{CC} × 0.75	_	v	
Low-level input voltage			1.8	_		V _{CC} × 0.12	_	V _{CC} × 0.12	v	
		—	2.3~5.5	_		V _{CC} × 0.25	_	V _{CC} × 0.25	V	
				1.8	1.7	1.8	_	1.7		
			I _{OH} = –100 μA	2.3	2.2	2.3		2.2		
			10Η = -100 μΛ	3.0	2.9	3.0		2.9		
High-level	V _{ОН}	V _{IN} = V _{IL}		4.5	4.4	4.5		4.4		v
output voltage	VОН	VIN = VIL	$I_{OH} = -8 \text{ mA}$	2.3	1.9	2.15	_	1.9	_	v
			I _{OH} = -16 mA	3.0	2.4	2.8		2.4		
		$I_{OH} = -24 \text{ mA}$	3.0	2.3	2.68		2.3			
			I _{OH} = -32 mA	4.5	3.8	4.2	_	3.8		
			I _{OL} = 100 μA	1.8	_	0	0.1		0.1	V
				2.3	_	0	0.1		0.1	
				3.0	_	0	0.1		0.1	
Low-level	Ve			4.5	_	0	0.1		0.1	
output voltage	VOL	$V_{IN} = V_{IL}$	$I_{OL} = 8 \text{ mA}$	2.3	_	0.1	0.3		0.3	
		I _{OL} = 16 mA	3.0	_	0.15	0.4	—	0.4		
		I _{OL} = 24 mA	3.0	_	0.22	0.55	_	0.55		
			I _{OL} = 32 mA	4.5	_	0.22	0.55	—	0.55	I
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0-5.5	_	_	±1	_	±10	μA
Power off leakage current	IOFF	V_{IN} or $V_{OUT} = 5.5 V$		0.0	_	_	1	_	10	μΑ
Quiescent supply current	ICC	$V_{IN} = V_{CC}$	$V_{IN} = V_{CC}$ or GND		_	_	2	_	20	μA

AC Characteristics (unless otherwise specified, Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40~85°C		Unit	
	Symbol		V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
Propagation delay time	^t pLH tpHL	$C_L = 15 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	1.8	2.0	4.4	9.5	2.0	10.0	ns
			2.5 ± 0.2	0.8	2.9	6.5	0.8	7.0	
			$\textbf{3.3}\pm\textbf{0.3}$	0.5	2.1	4.5	0.5	4.7	
			5.0 ± 0.5	0.5	1.8	3.9	0.5	4.1	
		$\begin{array}{l} C_{L} = 50 \; pF, \\ R_{L} = 500 \; \Omega \end{array}$	$\textbf{3.3}\pm\textbf{0.3}$	1.5	2.9	5.0	1.5	5.2	
			5.0 ± 0.5	0.8	2.4	4.3	0.8	4.5	
Input capacitance	C _{IN}		0~5.5	_	4	_	_	_	pF
Power dissipation capacitance	C _{PD}	(Note 4)	3.3		20		_	_	рF
			5.5		26		_	_	

Note 4: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

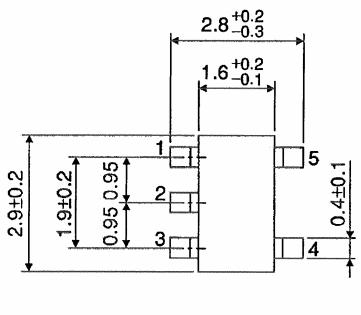
 $I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

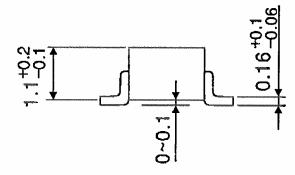
<u>TOSHIBA</u>

Package Dimensions

SSOP5-P-0.95

Unit : mm

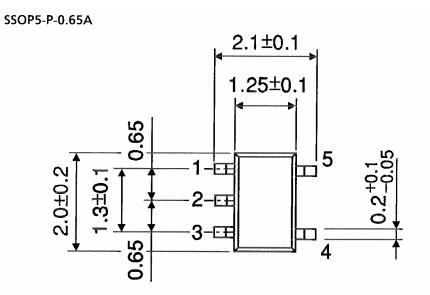


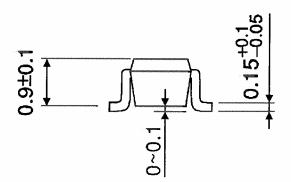


Weight: 0.016 g (typ.)

<u>TOSHIBA</u>

Package Dimensions





Weight: 0.006 g (typ.)

Unit : mm

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20070701-EN GENERAL

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